



# **isc Silicon NPN Power Transistor**

### **DESCRIPTION**

- Collector Current: I<sub>C</sub>= 4A
- · Low Collector Saturation Voltage
  - : V<sub>CE(sat)</sub>= 1.0V(Max)@I<sub>C</sub>= 2A
- · High Collector Power Dissipation
- Complement to Type 2SB857
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

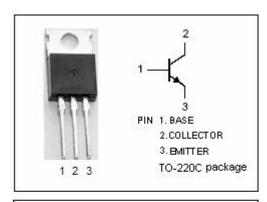


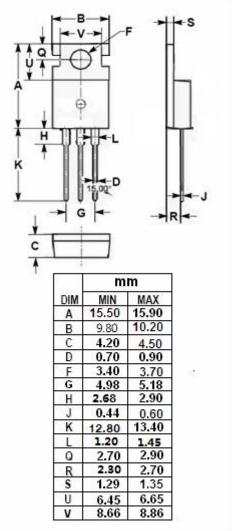
## **APPLICATIONS**

• Designed for low frequency power amplifier applications.

## ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
Vсво	Collector-Base Voltage	70	V
V <sub>CEO</sub>	Collector-Emitter Voltage	50	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
Ic	Collector Current-Continuous	4	Α
Ісм	Collector Current-Peak	8	А
Pc	Total Power Dissipation @ T <sub>C</sub> =25°C		W
TJ	Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature Range	-45~150	$^{\circ}$







# **isc Silicon NPN Power Transistor**

2SD1133

#### **ELECTRICAL CHARACTERISTICS**

T<sub>c</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 10mA ; R <sub>BE</sub> = ∞	50			V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> = 10 μ A ; I <sub>E</sub> = 0	70			V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = 10 μ A ; I <sub>C</sub> = 0	5			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 2A; I <sub>B</sub> = 0.2A			1.0	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = 1A; V <sub>CE</sub> = 4V			1.0	V
Ісво	Collector Cutoff Current	V <sub>CB</sub> = 50V ; I <sub>E</sub> = 0			1	μА
h <sub>FE-1</sub>	DC Current Gain	Ic= 1A; V <sub>CE</sub> = 4V	60		320	
h <sub>FE-2</sub>	DC Current Gain	Ic= 0.1A; V <sub>CE</sub> = 4V	35			
f⊤	Current-Gain—Bandwidth Product	I <sub>C</sub> = 0.5A; V <sub>CE</sub> = 4V		7		MHz

## ♦ h<sub>FE-1</sub> Classifications

В	С	D
60-120	100-200	160-320

### **NOTICE:**

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